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Details

Product Status	Obsolete
Core Processor	C166SV2
Core Size	16-Bit
Speed	80MHz
Connectivity	EBI/EMI, I ² C, LINbus, SPI, SSC, UART/USART, USI
Peripherals	I ² S, POR, PWM, WDT
Number of I/O	76
Program Memory Size	384KB (384K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	34K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 11x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP Exposed Pad
Supplier Device Package	PG-LQFP-100-8
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/xe164km48f80laafxuma1

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16-Bit Single-Chip
Real Time Signal Controller
XE164xM (XE166 Family)

1 Summary of Features

For a quick overview and easy reference, the features of the XE164xM are summarized here.

- High-performance CPU with five-stage pipeline and MPU
 - 12.5 ns instruction cycle at 80 MHz CPU clock (single-cycle execution)
 - One-cycle 32-bit addition and subtraction with 40-bit result
 - One-cycle multiplication (16×16 bit)
 - Background division ($32 / 16$ bit) in 21 cycles
 - One-cycle multiply-and-accumulate (MAC) instructions
 - Enhanced Boolean bit manipulation facilities
 - Zero-cycle jump execution
 - Additional instructions to support HLL and operating systems
 - Register-based design with multiple variable register banks
 - Fast context switching support with two additional local register banks
 - 16 Mbytes total linear address space for code and data
 - 1024 Bytes on-chip special function register area (C166 Family compatible)
 - Integrated Memory Protection Unit (MPU)
- Interrupt system with 16 priority levels for up to 96 sources
 - Selectable external inputs for interrupt generation and wake-up
 - Fastest sample-rate 12.5 ns
- Eight-channel interrupt-driven single-cycle data transfer with Peripheral Event Controller (PEC), 24-bit pointers cover total address space
- Clock generation from internal or external clock sources, using on-chip PLL or prescaler
- Hardware CRC-Checker with Programmable Polynomial to Supervise On-Chip Memory Areas
- On-chip memory modules
 - 8 Kbytes on-chip stand-by RAM (SBRAM)
 - 2 Kbytes on-chip dual-port RAM (DPRAM)
 - Up to 16 Kbytes on-chip data SRAM (DSRAM)
 - Up to 32 Kbytes on-chip program/data SRAM (PSRAM)
 - Up to 576 Kbytes on-chip program memory (Flash memory)
 - Memory content protection through Error Correction Code (ECC)
- On-Chip Peripheral Modules
 - Multi-functional general purpose timer unit with 5 timers
 - 16-channel general purpose capture/compare unit (CAPCOM2)

Table 5 Pin Definitions and Functions (cont'd)

Pin	Symbol	Ctrl.	Type	Function
6	P7.0	O0 / I	St/B	Bit 0 of Port 7, General Purpose Input/Output
	T3OUT	O1	St/B	GPT12E Timer T3 Toggle Latch Output
	T6OUT	O2	St/B	GPT12E Timer T6 Toggle Latch Output
	TDO_A	OH / IH	St/B	JTAG Test Data Output / DAP1 Input/Output If DAP pos. 0 or 2 is selected during start-up, an internal pull-down device will hold this pin low when nothing is driving it.
	ESR2_1	I	St/B	ESR2 Trigger Input 1
7	P7.3	O0 / I	St/B	Bit 3 of Port 7, General Purpose Input/Output
	EMUX1	O1	St/B	External Analog MUX Control Output 1 (ADC1)
	U0C1_DOUT	O2	St/B	USIC0 Channel 1 Shift Data Output
	U0C0_DOUT	O3	St/B	USIC0 Channel 0 Shift Data Output
	CCU62_CCP OS1A	I	St/B	CCU62 Position Input 1
	TMS_C	IH	St/B	JTAG Test Mode Selection Input If JTAG pos. C is selected during start-up, an internal pull-up device will hold this pin low when nothing is driving it.
	U0C1_DX0F	I	St/B	USIC0 Channel 1 Shift Data Input
8	P7.1	O0 / I	St/B	Bit 1 of Port 7, General Purpose Input/Output
	EXTCLK	O1	St/B	Programmable Clock Signal Output
	CCU62_CTR APA	I	St/B	CCU62 Emergency Trap Input
	BRKIN_C	I	St/B	OCDS Break Signal Input

Table 5 Pin Definitions and Functions (cont'd)

Pin	Symbol	Ctrl.	Type	Function
70	P10.5	O0 / I	St/B	Bit 5 of Port 10, General Purpose Input/Output
	U0C1_SCLK OUT	O1	St/B	USIC0 Channel 1 Shift Clock Output
	CCU60_COU T62	O2	St/B	CCU60 Channel 2 Output
	U2C0_DOUT	O3	St/B	USIC2 Channel 0 Shift Data Output
	AD5	OH / IH	St/B	External Bus Interface Address/Data Line 5
	U0C1_DX1B	I	St/B	USIC0 Channel 1 Shift Clock Input
71	P0.6	O0 / I	St/B	Bit 6 of Port 0, General Purpose Input/Output
	U1C1_DOUT	O1	St/B	USIC1 Channel 1 Shift Data Output
	TxDC1	O2	St/B	CAN Node 1 Transmit Data Output
	CCU61_COU T63	O3	St/B	CCU61 Channel 3 Output
	A6	OH	St/B	External Bus Interface Address Line 6
	U1C1_DX0A	I	St/B	USIC1 Channel 1 Shift Data Input
	CCU61_CTR APA	I	St/B	CCU61 Emergency Trap Input
72	U1C1_DX1B	I	St/B	USIC1 Channel 1 Shift Clock Input
	P10.6	O0 / I	St/B	Bit 6 of Port 10, General Purpose Input/Output
	U0C0_DOUT	O1	St/B	USIC0 Channel 0 Shift Data Output
	U1C0_SELO 0	O3	St/B	USIC1 Channel 0 Select/Control 0 Output
	AD6	OH / IH	St/B	External Bus Interface Address/Data Line 6
	U0C0_DX0C	I	St/B	USIC0 Channel 0 Shift Data Input
	U1C0_DX2D	I	St/B	USIC1 Channel 0 Shift Control Input
73	CCU60_CTR APA	I	St/B	CCU60 Emergency Trap Input

Table 5 Pin Definitions and Functions (cont'd)

Pin	Symbol	Ctrl.	Type	Function
73	P10.7	O0 / I	St/B	Bit 7 of Port 10, General Purpose Input/Output
	U0C1_DOUT	O1	St/B	USIC0 Channel 1 Shift Data Output
	CCU60_COU T63	O2	St/B	CCU60 Channel 3 Output
	AD7	OH / IH	St/B	External Bus Interface Address/Data Line 7
	U0C1_DX0B	I	St/B	USIC0 Channel 1 Shift Data Input
	CCU60_CCP OS0A	I	St/B	CCU60 Position Input 0
	T4INB	I	St/B	GPT12E Timer T4 Count/Gate Input
74	P0.7	O0 / I	St/B	Bit 7 of Port 0, General Purpose Input/Output
	U1C1_DOUT	O1	St/B	USIC1 Channel 1 Shift Data Output
	U1C0_SELO 3	O2	St/B	USIC1 Channel 0 Select/Control 3 Output
	TxDC3	O3	St/B	CAN Node 3 Transmit Data Output
	A7	OH	St/B	External Bus Interface Address Line 7
	U1C1_DX0B	I	St/B	USIC1 Channel 1 Shift Data Input
	CCU61_CTR APB	I	St/B	CCU61 Emergency Trap Input
78	P1.0	O0 / I	St/B	Bit 0 of Port 1, General Purpose Input/Output
	U1C0_MCLK OUT	O1	St/B	USIC1 Channel 0 Master Clock Output
	U1C0_SELO 4	O2	St/B	USIC1 Channel 0 Select/Control 4 Output
	A8	OH	St/B	External Bus Interface Address Line 8
	ESR1_3	I	St/B	ESR1 Trigger Input 3
	CCU62_CTR APB	I	St/B	CCU62 Emergency Trap Input
	T6INB	I	St/B	GPT12E Timer T6 Count/Gate Input

Table 5 Pin Definitions and Functions (cont'd)

Pin	Symbol	Ctrl.	Type	Function
84	P1.2	O0 / I	St/B	Bit 2 of Port 1, General Purpose Input/Output
	CCU62_CC62	O1	St/B	CCU62 Channel 2 Output
	U1C0_SELO6	O2	St/B	USIC1 Channel 0 Select/Control 6 Output
	U2C1_SCLKOUT	O3	St/B	USIC2 Channel 1 Shift Clock Output
	A10	OH	St/B	External Bus Interface Address Line 10
	ESR1_4	I	St/B	ESR1 Trigger Input 4
	CCU61_T12HRB	I	St/B	External Run Control Input for T12 of CCU61
	CCU62_CC62INA	I	St/B	CCU62 Channel 2 Input
	U2C1_DX0D	I	St/B	USIC2 Channel 1 Shift Data Input
	U2C1_DX1C	I	St/B	USIC2 Channel 1 Shift Clock Input
85	P10.12	O0 / I	St/B	Bit 12 of Port 10, General Purpose Input/Output
	U1C0_DOUT	O1	St/B	USIC1 Channel 0 Shift Data Output
	TxDC2	O2	St/B	CAN Node 2 Transmit Data Output
	TDO_B	OH / IH	St/B	JTAG Test Data Output / DAP1 Input/Output If DAP pos. 1 is selected during start-up, an internal pull-down device will hold this pin low when nothing is driving it.
	AD12	OH / IH	St/B	External Bus Interface Address/Data Line 12
	U1C0_DX0C	I	St/B	USIC1 Channel 0 Shift Data Input
	U1C0_DX1E	I	St/B	USIC1 Channel 0 Shift Clock Input

Table 5 Pin Definitions and Functions (cont'd)

Pin	Symbol	Ctrl.	Type	Function
93	P1.6	O0 / I	St/B	Bit 6 of Port 1, General Purpose Input/Output
	CCU62_CC61	O1 / I	St/B	CCU62 Channel 1 Output
	U1C1_SELO2	O2	St/B	USIC1 Channel 1 Select/Control 2 Output
	U2C0_DOUT	O3	St/B	USIC2 Channel 0 Shift Data Output
	A14	OH	St/B	External Bus Interface Address Line 14
	U2C0_DX0D	I	St/B	USIC2 Channel 0 Shift Data Input
	CCU62_CC61INA	I	St/B	CCU62 Channel 1 Input
94	P1.7	O0 / I	St/B	Bit 7 of Port 1, General Purpose Input/Output
	CCU62_CC60	O1	St/B	CCU62 Channel 0 Output
	U1C1_MCLKOUT	O2	St/B	USIC1 Channel 1 Master Clock Output
	U2C0_SCLKOUT	O3	St/B	USIC2 Channel 0 Shift Clock Output
	A15	OH	St/B	External Bus Interface Address Line 15
	U2C0_DX1C	I	St/B	USIC2 Channel 0 Shift Clock Input
	CCU62_CC60INA	I	St/B	CCU62 Channel 0 Input
95	XTAL2	O	Sp/M	Crystal Oscillator Amplifier Output
96	XTAL1	I	Sp/M	Crystal Oscillator Amplifier Input To clock the device from an external source, drive XTAL1, while leaving XTAL2 unconnected. Voltages on XTAL1 must comply to the core supply voltage V_{DDIM} .
	ESR2_9	I	St/B	ESR2 Trigger Input 9

3.2 External Bus Controller

All external memory access operations are performed by a special on-chip External Bus Controller (EBC). The EBC also controls access to resources connected to the on-chip LxBus (MultiCAN and the USIC modules). The LxBus is an internal representation of the external bus that allows access to integrated peripherals and modules in the same way as to external components.

The EBC can be programmed either to Single Chip Mode, when no external memory is required, or to an external bus mode with the following selections¹⁾:

- Address Bus Width with a range of 0 ... 24-bit
- Data Bus Width 8-bit or 16-bit
- Bus Operation Multiplexed or Demultiplexed

The bus interface uses Port 10 and Port 2 for addresses and data. In the demultiplexed bus modes, the lower addresses are output separately on Port 0 and Port 1. The number of active segment address lines is selectable, restricting the external address space to 8 Mbytes ... 64 Kbytes. This is required when interface lines shall be assigned to Port 2.

External $\overline{\text{CS}}$ signals (address windows plus default) can be generated and output on Port 4 in order to save external glue logic. External modules can be directly connected to the common address/data bus and their individual select lines.

Important timing characteristics of the external bus interface are programmable (with registers TCONCSx/FCONCSx) to allow the user to adapt it to a wide range of different types of memories and external peripherals.

Access to very slow memories or modules with varying access times is supported by a special 'Ready' function. The active level of the control input signal is selectable.

In addition, up to four independent address windows may be defined (using registers ADDRSELx) to control access to resources with different bus characteristics. These address windows are arranged hierarchically where window 4 overrides window 3, and window 2 overrides window 1. All accesses to locations not covered by these four address windows are controlled by TCONCS0/FCONCS0. The currently active window can generate a chip select signal.

The external bus timing is based on the rising edge of the reference clock output CLKOUT. The external bus protocol is compatible with that of the standard C166 Family.

¹⁾ Bus modes are switched dynamically if several address windows with different mode settings are used.

3.14 MultiCAN Module

The MultiCAN module contains independently operating CAN nodes with Full-CAN functionality which are able to exchange Data and Remote Frames using a gateway function. Transmission and reception of CAN frames is handled in accordance with CAN specification V2.0 B (active). Each CAN node can receive and transmit standard frames with 11-bit identifiers as well as extended frames with 29-bit identifiers.

All CAN nodes share a common set of message objects. Each message object can be individually allocated to one of the CAN nodes. Besides serving as a storage container for incoming and outgoing frames, message objects can be combined to build gateways between the CAN nodes or to set up a FIFO buffer.

Note: The number of CAN nodes and message objects depends on the selected device type.

The message objects are organized in double-chained linked lists, where each CAN node has its own list of message objects. A CAN node stores frames only into message objects that are allocated to its own message object list and it transmits only messages belonging to this message object list. A powerful, command-driven list controller performs all message object list operations.

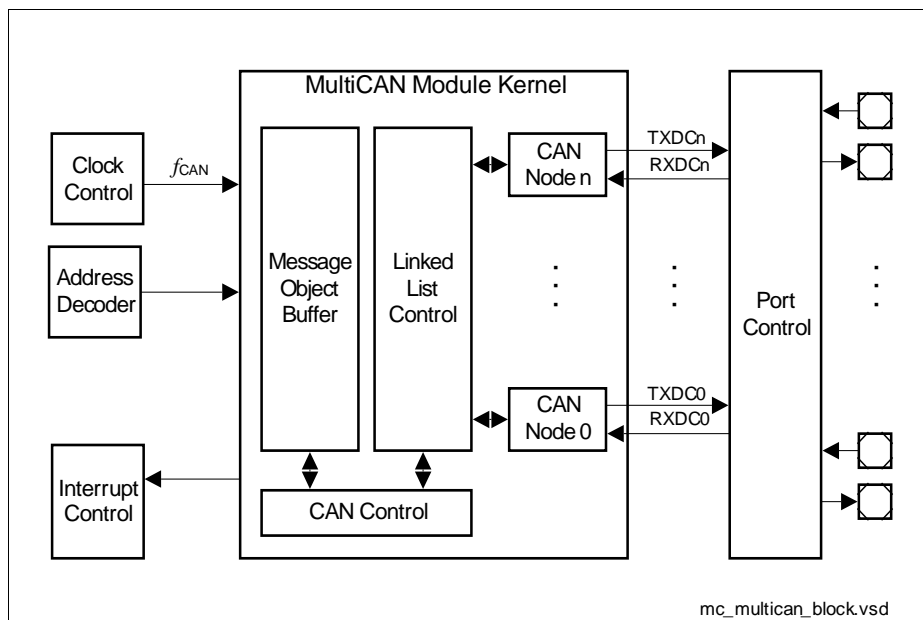


Figure 12 Block Diagram of MultiCAN Module

Functional Description

Table 10 Instruction Set Summary (cont'd)

Mnemonic	Description	Bytes
NOP	Null operation	2
CoMUL/CoMAC	Multiply (and accumulate)	4
CoADD/CoSUB	Add/Subtract	4
Co(A)SHR	(Arithmetic) Shift right	4
CoSHL	Shift left	4
CoLOAD/STORE	Load accumulator/Store MAC register	4
CoCMP	Compare	4
CoMAX/MIN	Maximum/Minimum	4
CoABS/CoRND	Absolute value/Round accumulator	4
CoMOV	Data move	4
CoNEG/NOP	Negate accumulator/Null operation	4

- 1) The Enter Power Down Mode instruction is not used in the XE164xM, due to the enhanced power control scheme. PWRDN will be correctly decoded, but will trigger no action.

4.2 DC Parameters

These parameters are static or average values that may be exceeded during switching transitions (e.g. output current).

Leakage current is strongly dependent on the operating temperature and the voltage level at the respective pin. The maximum values in the following tables apply under worst case conditions, i.e. maximum temperature and an input level equal to the supply voltage.

The value for the leakage current in an application can be determined by using the respective leakage derating formula (see tables) with values from that application.

The pads of the XE164xM are designed to operate in various driver modes. The DC parameter specifications refer to the pad current limits specified in [Section 4.6.4](#).

Supply Voltage Restrictions

The XE164xM can operate within a wide supply voltage range from 3.0 V to 5.5 V. However, during operation this supply voltage must remain within 10 percent of the selected nominal supply voltage. It cannot vary across the full operating voltage range.

Because of the supply voltage restriction and because electrical behavior depends on the supply voltage, the parameters are specified separately for the upper and the lower voltage range.

During operation, the supply voltages may only change with a maximum speed of $dV/dt < 1 \text{ V/ms}$.

During power-on sequences, the supply voltages may only change with a maximum speed of $dV/dt < 5 \text{ V/}\mu\text{s}$, i.e. the target supply voltage may be reached earliest after approx. 1 μs .

Note: To limit the speed of supply voltage changes, the employment of external buffer capacitors at pins V_{DDPA}/V_{DDPB} is recommended.

4.2.1 DC Parameters

Keeping signal levels within the limits specified in this table ensures operation without overload conditions. For signal levels outside these specifications, also refer to the specification of the overload current I_{OV} .

Note: Operating Conditions apply.

Table 13 is valid under the following conditions:

$V_{DDP} \geq 4.5 \text{ V}$; $V_{DDPtyp} = 5 \text{ V}$; $V_{DDP} \leq 5.5 \text{ V}$

Table 13 DC Characteristics for Upper Voltage Range

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Pin capacitance (digital inputs/outputs). To be doubled for double bond pins. ¹⁾	$C_{IO} \text{ CC}$	–	–	10	pF	not subject to production test
Input Hysteresis ²⁾	$HYS \text{ CC}$	$0.11 \times V_{DDP}$	–	–	V	$R_S = 0 \text{ Ohm}$
Absolute input leakage current on pins of analog ports ³⁾	$ I_{OZ1} \text{ CC}$	–	10	200	nA	$V_{IN} > 0 \text{ V}$; $V_{IN} < V_{DDP}$
Absolute input leakage current for all other pins. To be doubled for double bond pins. ³⁾¹⁾⁴⁾	$ I_{OZ2} \text{ CC}$	–	0.2	5	μA	$T_J \leq 110 \text{ }^\circ\text{C}$; $V_{IN} < V_{DDP}$; $V_{IN} > V_{SS}$
		–	0.2	15	μA	$T_J \leq 150 \text{ }^\circ\text{C}$; $V_{IN} < V_{DDP}$; $V_{IN} > V_{SS}$
Pull Level Force Current ⁵⁾	$ I_{PLF} \text{ SR}$	250	–	–	μA	⁶⁾
Pull Level Keep Current ⁷⁾	$ I_{PLK} \text{ SR}$	–	–	30	μA	⁶⁾
Input high voltage (all except XTAL1)	$V_{IH} \text{ SR}$	$0.7 \times V_{DDP}$	–	$V_{DDP} + 0.3$	V	
Input low voltage (all except XTAL1)	$V_{IL} \text{ SR}$	-0.3	–	$0.3 \times V_{DDP}$	V	
Output High voltage ⁸⁾	$V_{OH} \text{ CC}$	$V_{DDP} - 1.0$	–	–	V	$I_{OH} \geq I_{OHmax}$
		$V_{DDP} - 0.4$	–	–	V	$I_{OH} \geq I_{OHnom}$ ⁹⁾

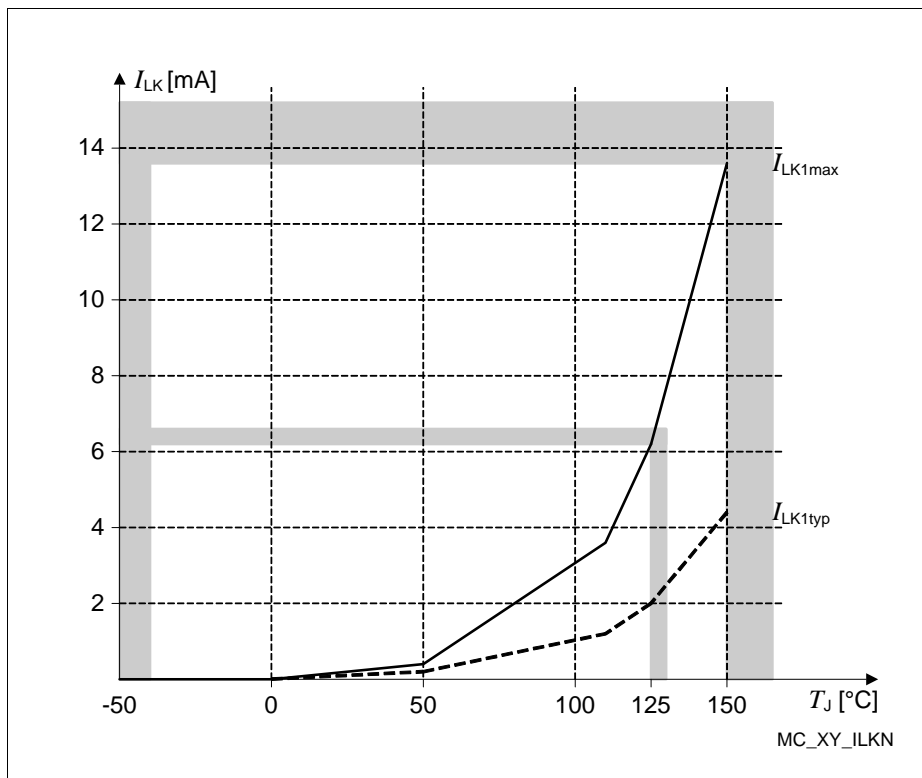


Figure 15 Leakage Supply Current as a Function of Temperature

Electrical Parameters

The timing in the AC Characteristics refers to TCSs. Timing must be calculated using the minimum TCS possible under the given circumstances.

The actual minimum value for TCS depends on the jitter of the PLL. Because the PLL is constantly adjusting its output frequency to correspond to the input frequency (from crystal or oscillator), the accumulated jitter is limited. This means that the relative deviation for periods of more than one TCS is lower than for a single TCS (see formulas and [Figure 20](#)).

This is especially important for bus cycles using waitstates and for the operation of timers, serial interfaces, etc. For all slower operations and longer periods (e.g. pulse train generation or measurement, lower baudrates, etc.) the deviation caused by the PLL jitter is negligible.

The value of the accumulated PLL jitter depends on the number of consecutive VCO output cycles within the respective timeframe. The VCO output clock is divided by the output prescaler K2 to generate the system clock signal f_{SYS} . The number of VCO cycles is $K2 \times T$, where T is the number of consecutive f_{SYS} cycles (TCS).

The maximum accumulated jitter (long-term jitter) D_{Tmax} is defined by:

$$D_{Tmax} [ns] = \pm(220 / (K2 \times f_{SYS}) + 4.3)$$

This maximum value is applicable, if either the number of clock cycles $T > (f_{SYS} / 1.2)$ or the prescaler value $K2 > 17$.

In all other cases for a timeframe of $T \times TCS$ the accumulated jitter D_T is determined by:

$$D_T [ns] = D_{Tmax} \times [(1 - 0.058 \times K2) \times (T - 1) / (0.83 \times f_{SYS} - 1) + 0.058 \times K2]$$

f_{SYS} in [MHz] in all formulas.

Example, for a period of 3 TCSs @ 33 MHz and $K2 = 4$:

$$D_{max} = \pm(220 / (4 \times 33) + 4.3) = 5.97 \text{ ns (Not applicable directly in this case!)}$$

$$\begin{aligned} D_3 &= 5.97 \times [(1 - 0.058 \times 4) \times (3 - 1) / (0.83 \times 33 - 1) + 0.058 \times 4] \\ &= 5.97 \times [0.768 \times 2 / 26.39 + 0.232] \\ &= 1.7 \text{ ns} \end{aligned}$$

Example, for a period of 3 TCSs @ 33 MHz and $K2 = 2$:

$$D_{max} = \pm(220 / (2 \times 33) + 4.3) = 7.63 \text{ ns (Not applicable directly in this case!)}$$

$$\begin{aligned} D_3 &= 7.63 \times [(1 - 0.058 \times 2) \times (3 - 1) / (0.83 \times 33 - 1) + 0.058 \times 2] \\ &= 7.63 \times [0.884 \times 2 / 26.39 + 0.116] \\ &= 1.4 \text{ ns} \end{aligned}$$

PLL frequency band selection

Different frequency bands can be selected for the VCO so that the operation of the PLL can be adjusted to a wide range of input and output frequencies:

Table 23 System PLL Parameters

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
VCO output frequency (VCO controlled)	f_{VCO} CC	50	–	110	MHz	VCOSSEL = 00 _B
		100	–	160	MHz	VCOSSEL = 01 _B
VCO output frequency (VCO free-running)	f_{VCO} CC	10	–	40	MHz	VCOSSEL = 00 _B
		20	–	80	MHz	VCOSSEL = 01 _B

4.6.2.2 Wakeup Clock

When wakeup operation is selected (SYSCON0.CLKSEL = 00_B), the system clock is derived from the low-frequency wakeup clock source:

$$f_{SYS} = f_{WU}$$

In this mode, a basic functionality can be maintained without requiring an external clock source and while minimizing the power consumption.

4.6.2.3 Selecting and Changing the Operating Frequency

When selecting a clock source and the clock generation method, the required parameters must be carefully written to the respective bit fields, to avoid unintended intermediate states.

Many applications change the frequency of the system clock (f_{SYS}) during operation in order to optimize system performance and power consumption. Changing the operating frequency also changes the switching currents, which influences the power supply.

To ensure proper operation of the on-chip EVRs while they generate the core voltage, the operating frequency shall only be changed in certain steps. This prevents overshoots and undershoots of the supply voltage.

To avoid the indicated problems, recommended sequences are provided which ensure the intended operation of the clock system interacting with the power system.

Please refer to the Programmer's Guide.

4.6.5 External Bus Timing

The following parameters specify the behavior of the XE164xM bus interface.

Note: These parameters are not subject to production test but verified by design and/or characterization.

Note: Operating Conditions apply.

Bus Interface Performance Limits

The output frequency at the bus interface pins is limited by the performance of the output drivers. The fast clock driver (used for CLKOUT) can drive 80-MHz signals, the standard drivers can drive 40-MHz signals

Therefore, the speed of the EBC must be limited, either by limiting the system frequency to $f_{SYS} \leq 80$ MHz or by adding waitstates so that signal transitions have a minimum distance of 12.5 ns.

For a description of the bus protocol and the programming of its variable timing parameters, please refer to the User's Manual.

Table 27 EBC Parameters

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
CLKOUT Cycle Time ¹⁾	t_5 CC	—	$1 / f_{SYS}$	—	ns	
CLKOUT high time	t_6 CC	2	—	—		
CLKOUT low time	t_7 CC	2	—	—		
CLKOUT rise time	t_8 CC	—	—	3	ns	
CLKOUT fall time	t_9 CC	—	—	3		

1) The CLKOUT cycle time is influenced by PLL jitter. For longer periods the relative deviation decreases (see PLL deviation formula).

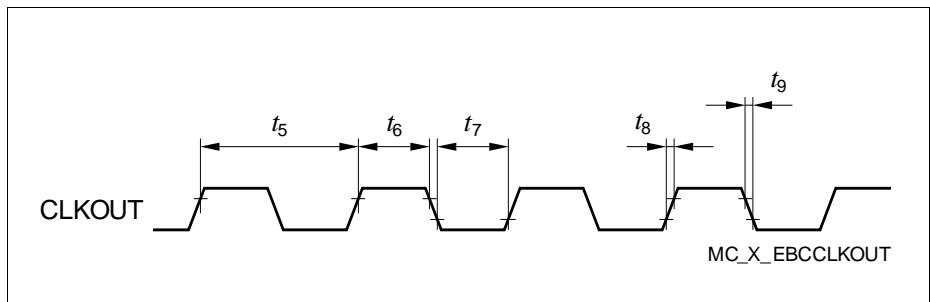


Figure 22 CLKOUT Signal Timing

4.6.6 Synchronous Serial Interface Timing

The following parameters are applicable for a USIC channel operated in SSC mode.

Note: These parameters are not subject to production test but verified by design and/or characterization.

Note: Operating Conditions apply; $C_L = 20$ pF.

Table 31 USIC SSC Master Mode Timing for Upper Voltage Range

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Slave select output SELO active to first SCLKOUT transmit edge	t_1 CC	$t_{SYS} - 8^{1)}$	—	—	ns	
Slave select output SELO inactive after last SCLKOUT receive edge	t_2 CC	$t_{SYS} - 6^{1)}$	—	—	ns	
Data output DOUT valid time	t_3 CC	-6	—	9	ns	
Receive data input setup time to SCLKOUT receive edge	t_4 SR	31	—	—	ns	
Data input DX0 hold time from SCLKOUT receive edge	t_5 SR	-4	—	—	ns	

1) $t_{SYS} = 1 / f_{SYS}$

Table 32 USIC SSC Master Mode Timing for Lower Voltage Range

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Slave select output SELO active to first SCLKOUT transmit edge	t_1 CC	$t_{SYS} - 10^{1)}$	—	—	ns	
Slave select output SELO inactive after last SCLKOUT receive edge	t_2 CC	$t_{SYS} - 9^{1)}$	—	—	ns	
Data output DOUT valid time	t_3 CC	-7	—	11	ns	

Table 36 DAP Interface Timing for Lower Voltage Range

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
DAP0 clock period	t_{11} SR	25 ¹⁾	—	—	ns	
DAP0 high time	t_{12} SR	8	—	—	ns	
DAP0 low time	t_{13} SR	8	—	—	ns	
DAP0 clock rise time	t_{14} SR	—	—	4	ns	
DAP0 clock fall time	t_{15} SR	—	—	4	ns	
DAP1 setup to DAP0 rising edge	t_{16} SR	6	—	—	ns	pad_type= standard
DAP1 hold after DAP0 rising edge	t_{17} SR	6	—	—	ns	pad_type= standard
DAP1 valid per DAP0 clock period ²⁾	t_{19} CC	12	17	—	ns	pad_type= standard

1) The debug interface cannot operate faster than the overall system, therefore $t_{11} \geq t_{SYS}$.

2) The Host has to find a suitable sampling point by analyzing the sync telegram response.

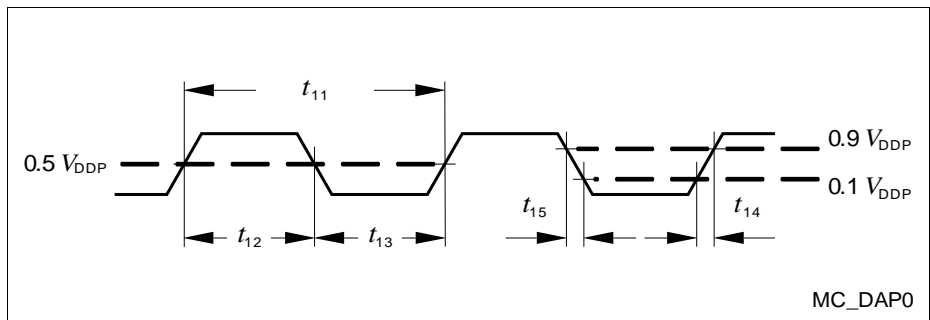


Figure 27 Test Clock Timing (DAP0)

5 Package and Reliability

The XE166 Family devices use the package type PG-LQFP (Plastic Green - Low Profile Quad Flat Package). The following specifications must be regarded to ensure proper integration of the XE164xM in its target environment.

5.1 Packaging

These parameters specify the packaging rather than the silicon.

Table 39 Package Parameters (PG-LQFP-100-8)

Parameter	Symbol	Limit Values		Unit	Notes
		Min.	Max.		
Exposed Pad Dimension	$Ex \times Ey$	–	6.2×6.2	mm	–
Power Dissipation	P_{DISS}	–	1.0	W	–
Thermal resistance Junction-Ambient	$R_{\Theta JA}$	–	47	K/W	No thermal via ¹⁾
			29	K/W	4-layer, no pad ²⁾
			23	K/W	4-layer, pad ³⁾

1) Device mounted on a 2-layer JEDEC board (according to JESD 51-3) or a 4-layer board without thermal vias; exposed pad not soldered.

2) Device mounted on a 4-layer JEDEC board (according to JESD 51-7) with thermal vias; exposed pad not soldered.

3) Device mounted on a 4-layer JEDEC board (according to JESD 51-7) with thermal vias; exposed pad soldered to the board.

Note: To improve the EMC behavior, it is recommended to connect the exposed pad to the board ground, independent of the thermal requirements.

Board layout examples are given in an application note.

Package Compatibility Considerations

The XE164xM is a member of the XE166 Family of microcontrollers. It is also compatible to a certain extent with members of similar families or subfamilies.

Each package is optimized for the device it houses. Therefore, there may be slight differences between packages of the same pin-count but for different device types. In particular, the size of the Exposed Pad (if present) may vary.

If different device types are considered or planned for an application, it must be ensured that the board layout fits all packages under consideration.

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